

# Abstracts

## GaAs Dual-Gate FET for Operation Up to K-Band (Comments)

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H.-O. Vickes. "GaAs Dual-Gate FET for Operation Up to K-Band (Comments)." 1988  
*Transactions on Microwave Theory and Techniques* 36.6 (Jun. 1988 [T-MTT]): 1111-1111.

In the above paper, the authors have discussed some fundamental properties of dual-gate FET's valid from X-band up to K-band.

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